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Adapting of sol-gel process for preparation of TiB₂ powder from low-cost precursors

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Abstract

Sol-gel process has been used for preparation of low-cost titanium diboride (TiB₂) and titanium carbide (TiC) gels and powders. In this process citric acid is used to chelate titanium and boron precursors and ethylene glycol for reaction with this chelate to form organic esters. Thermal behavior of homogeneous gel and relationship between processing parameters and microstructure of powders has been determined. XRD and Raman spectroscopy have been used for a detection of changes during the crystallization. Carbothermal reduction of the gel revealed the formation of TiB₂ and TiC at 1200 °C for 2 h. Well shaped ball-like TiC crystals with the particle size about 200 nm and hexagonal plate-like TiB₂ grains with the particle size about 2 μ m and thickness 200 nm were formed at 1300 °C for 1 h. © 2007 Elsevier Ltd. All rights reserved.

Keywords: Sol-gel processes; Precursor-organic; Borides; Carbides; Raman spectroscopy

1. Introduction

Polycrystalline ceramics based on TiB₂ have received considerable attention as cutting tools, electrodes for liquid aluminium and wall materials for nuclear fusion.¹

Commercial methods used for synthesis of TiB₂ powders are mostly based on high-temperature carbothermic reduction of a mixture of rutile and boric acid. However, this reaction is highly exothermic and needs temperatures above $1800 \,^{\circ}\text{C.}^2$

By comparison, self-propagating high-temperature synthesis (SHS) has attracted the attention of researchers and companies for manufacturing high-purity TiB_2 and titanium diboridebased composites.^{3–7} The system usually uses powdered metal—magnesium (Mg) or aluminum (Al) and titanium oxide (TiO₂) and boron oxide (B₂O₃). Another modification of this synthesis is using NaCl as an SHS diluent.^{8,9} These materials are mixed and placed into a high-temperature crucible. The mixture is then ignited and the reaction between the two oxides and the metal powder proceeds to completion. Once started, the self-sustaining reaction reaches temperatures of more than 2000 °C.

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Submicron and nanocrystalline titanium diboride powder with average particle size less then 200 and 50 nm can be produced by ball-milling a mixture of TiO_2 , B_2O_3 and Mg metal for 15 and 100 h respectively, as reported by Welham.¹⁰ When a mixture of pure Ti and BN powders has been used, 2 h of highenergy ball-milling has started the reaction to produce TiN and TiB₂ mixture by displacement reaction. After 16 h of composite powder milling, 10 nm crystallites of TiN and TiB₂ have been obtained.¹¹

Nanocrystalline TiB₂ with a narrow particle size distribution (~15 nm) has been also prepared by the reduction-boronation method at 400 °C in which boron tribromide (BBr₃) and Ti powder have been used as a source material and metallic sodium as a reductant.¹² The same authors reported a facile one-step route to nanocrystalline TiB₂ powders by solvothermal reaction of TiCl₄ with NaBH₄ in the temperature range of 500–700 °C in an autoclave.¹³

Although ultra-fine TiB₂ powders and their composites have been successfully synthesized by either high-energy ball-milling or solvothermal route in autoclave, there is still potential in preparation of cheap TiB₂ powder. In the present study we report for a first time adapted Pechini method for synthesis of nonoxide powders. Low-cost inorganic precursors (TiCl₄ and B₂O₃) have been chelated by citric acid and polymerized by ethylene glycol to form polymer-derived ceramic precursor.

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Fig. 1. XRD analysis revealed the sequence in carbothermal reduction of polymer-derived ceramic gels of Ti and B during heat treatment.

2. Experimental

Titanium diboride (TiB₂) powder was prepared by carbothermic reduction of stoichiometric mixture of titanium tetrachloride (TiCl₄, 99.9%, Acros Organics, Belgium) and boron oxide (B_2O_3 , Rio Tinto Borax, CA, USA). Citric acid (CA) was used to chelate with Ti and B precursors by forming a polybasic acid. After homogenization of the solution containing cations, ethylene glycol (EG) was added in CA:EG ratio of 2:3, to promote mixed citrate polymerization. During evaporation of water from system, gelation occurred. Obtained gel was dried at 180 °C for 48 h and crushed prior to heat treatment. Formed organic ester was used as a carbon source. Heat treatment was done in tube furnace at different temperatures in flowing Ar atmosphere. The schematic reaction is suggested as follows:

$$TiCl_4 + B_2O_3 + H_2O + C_6H_8O_7 + C_2H_6O_2$$

$$\rightarrow TiB_2 + CO + H_2O + HCl$$

Phase analysis was conducted and recorded using powder-XRD X-pert (Philips). Field emission scanning electron microscopy (FESEM, Carl Zeiss SUPRATM 40VP) was used to study crystal size and morphology of TiB₂ powder. EDX spectra were recorded to identify chemistry of different morphologies obtained in samples. Raman spectra were measured with the spectrometer Aramis (Horiba Jobin Yvon) equipped with 532 nm laser.



Fig. 2. (a) Raman spectra of polymer-derived ceramic resins obtained by heating at 700, 1000 and $1100 \,^{\circ}$ C for 2 h in flowing argon. (b) Raman spectra of samples already containing TiB₂ at temperatures of $1200 \,^{\circ}$ C/2 h, $1300 \,^{\circ}$ C/1 h and $1300 \,^{\circ}$ C/2 h. (c) Raman spectra of commercial TiB₂ powder (H.C. Starck, Germany).

3. Results and discussion

3.1. XRD and Raman spectroscopy

The XRD patterns (Fig. 1) of gel samples heated at various temperatures show sequences in TiB₂ powder evolution. After heat treatment at 700 °C/2 h only titanium dioxide crystalline phases were formed. As further revealed by Raman spectroscopy (Fig. 2a), these phases were assigned to anatase with bands at

148, 200, 397, 516 and 637 cm⁻¹ and rutile at 445 and 611 cm⁻¹. Also Nikolova et al.¹⁴ observed rutile peaks at 445 and 610 cm⁻¹ in TiC thin film annealed at 1000 °C in an H₂O/HCl gas mixture.

At 1000 °C/2 h rutile and carbon were identified together with some very weak unidentified peaks. Raman spectra revealed only major amorphous carbon phase with characteristic bands at 1368 and 1600 cm⁻¹. Lohse et al.¹⁵ recorded the spectra taken from five different particles of the as-received carbon starting powder



Fig. 3. Scanning electron microscope micrograph of TiB₂ powder heat treated in flowing Ar atmosphere at: (a) 1200 °C for 2 h, (b) 1150 °C for 5 h, (c) 1300 °C for 2 h, (d) 1400 °C for 2 h and (e) 1500 °C for 2 h.

and they found two strong peaks at approximately 1340 and $1590 \,\mathrm{cm}^{-1}$. These peaks were associated with the A 1g and E 2g vibrational modes of graphite.^{16,17}

XRD spectrum at 1100 °C/2 h revealed titanium borate (TiBO₃) as a new phase, the intensity of rutile slightly decreased and the intensity of graphite almost disappeared. Strongly reduced graphite bands were also observed in Raman spectrum. Moreover, very weak new bands at 256, 379, 932 and 1199 cm⁻¹ were observed. These bands could be assigned to new phase identified by XRD as titanium borate.

At 1200 °C/2 h the XRD spectrum has been totally changed and titanium carbide (TiC) and titanium boride (TiB₂) appeared. Very weak peak of TiO₂ was also found. In the Raman spectrum titanium dioxide was identified as anatase phase.

XRD spectrum of sample annealed at 1300 °C for 1 h shows only TiC and TiB₂ phases without presence of any other phase. However, Raman spectra revealed that small amount of anatase was present also in this sample. Wide bands found at 258, 396 and 610 cm^{-1} in Raman spectra (Fig. 2b) were assigned to the mixture of TiB₂ and TiC because of very near distribution of original bands of TiC at 260, 420 and 605 cm^{-115} and that obtained from the commercial H.C. Starck powder of TiB₂ at 262, 404, and 598 cm⁻¹ (Fig. 2c). This correlates very well with spectra obtained by XRD.

XRD pattern of samples heated at $1300 \degree C/2 h$ and $1400 \degree C/2 h$ showed similar phase composition. The intensity of TiB₂ increased with temperature. The intensity of TiC with temperature decreased while that of TiO₂ remained unchanged. It is interesting to note that the intensity of anatase at $1200 \degree C/2 h$ and $1300 \degree C/1 h$ was almost zero and then increased again when the sample was heated at $1300 \degree C$ for 2 h. It indicates the preferable reaction between TiC and amorphous B forming TiB₂ and C at this temperature.

Additionally, new sample was prepared to observe the content of anatase at 1600 °C. XRD spectrum was recorded and revealed that titanium dioxide remained still in TiB₂–TiC powder.

Summarizing the results obtained by XRD and Raman spectroscopy the carbothermal reduction of polymer-derived ceramic precursor producing mixed TiB₂/TiC powder follows the schematic pathway:

$$TiCl_4 + B_2O_3 + H_2O + C_6H_8O_7 + C_2H_6O_2$$

$$\xrightarrow{700 \,^{\circ}C} TiO_2 + C + B \xrightarrow{1000 \,^{\circ}C} TiO_2 + C + B$$

$$\xrightarrow{1100 \,^{\circ}C} TiBO_3 + TiO_2 + B + C$$

$$\xrightarrow{1200 \,^{\circ}C} TiC + TiB_2 + TiBO_3 \xrightarrow{1300 \,^{\circ}C} TiB_2 + TiC + TiO_2$$

However, boron was not detected by XRD or Raman, due to its amorphous state. According to the scheme boron reacts first with TiO₂ at 1100 °C to form TiBO₃. No other boron based crystalline phase was detected. Pure TiB₂ powder could not be synthesized from equal molar TiCl₄ and B₂O₃ precursors even at temperature of 1600 °C in protecting argon atmosphere. There were always byproducts of TiC and TiO₂.

3.2. SEM and EDX analysis

Fig. 3a–e shows the microstructure evolution of polymer derived TiB₂ precursors heat treated at 1150-1500 °C in flowing argon atmosphere.

At temperature $1200 \circ C/2 h$ (Fig. 3a) the morphology of the powder appeared highly porous with formation of necks among the crystals. Crystal size of the synthesized TiB₂ based powder was about 200 nm, which was agglomerated. However, Fig. 3b shows that crystals of TiB₂ have a tendency to grow also at lower calcination temperature ($1150 \circ C$) during longer soaking time (5 h). The spherical nanoparticles formed pre-sintered clusters. At higher temperatures these oriented clusters formed highly faceted TiB₂ hexagonal mica-like crystals and spherical TiC particles as shown in Fig. 3c–e. EDX analysis was recorded to distinguish this bimodal morphology of powders (Fig. 4a and b).

In samples prepared at 1500 °C for 2 h mica-like hexagonal crystals were sintered together forming hexagonal single crystals without further evidence of mica-like sheets. Similar morphology of TiB₂ particles was observed also by Welham¹⁰ after 15 h ball-milling of TiO₂, B₂O₃ and Mg powders. The par-



Fig. 4. EDX spectra of sample treated at $1400 \,^{\circ}$ C for 2 h. (a) Spectrum of hexagonal plates revealed presence of Ti and B and (b) spectrum of spherical particles revealed presence of Ti and C.

ticles size of spherical TiC increased from 200 nm at $1300 \degree$ C/2 h to 400-500 nm at $1500 \degree$ C/2 h.

4. Conclusions

Titanium diboride powder has been successfully synthesized by esterification of Ti and B inorganic precursors followed by heat treatment in argon atmosphere. It was found that byproducts of TiC and TiO₂ were present in the as-synthesized powders even at temperature of 1600 °C for 2 h.

Based on XRD and Raman analysis a reaction scheme was suggested for single steps of carbothermal reduction of Ti and B species prepared from the precursors by this method.

SEM and EDX analysis revealed well shaped hexagonal plate-like TiB₂ crystals with the particle size about 2 μ m and thickness 200 nm, and spherical TiC particles with the crystal size about 200 nm prepared at 1300 °C for 1 h.

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